

Features

- Zero Forward/Reverse Recovery Current
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on V_F
- Temperature Independent Switching Behavior
- High surge current capability
- 100% avalanche tested

Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- High Temperature Application
- No Switching loss
- Hard Switching & Higher Reliability
- Environmental Protection

Applications

- Servo Drives
- Solar / Wind Inverters
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies



TO-247-2



Maximum Ratings (T_C=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}		1200	V
Continuous Forward Current	I_F	T _C =25°C	50	A
		T _C =135°C	21	
		T _C =150°C	15	
Non repetitive Forward Surge Current	I_{FSM}	T _C = 25°C, t _p =10 ms, Half Sine Pulse	130	A
		T _C = 110°C, t _p =10 ms, Half Sine Pulse	120	
Repetitive peak Forward Surge Current	I_{FRM}	T _C = 25°C, t _p =10 ms, Freq = 0.1Hz, 100 cycles, Half Sine Pulse	100	A
		T _C = 110°C, t _p =10 ms, Freq = 0.1Hz, 100 cycles, Half Sine Pulse	90	
Total power dissipation	P_D	T _C =25°C	240	W
		T _C =110°C	98	
Single Pulse Avalanche Energy	E_{AS}	L=2mH, I _{AS} =10A	100	mJ
Diode dv/dt ruggedness	dv/dt	V _R = 0-1200V	80	V/ns
Operating Junction Temperature	T _J		-55 to 175	°C
Storage Temperature	T _{STG}		-55 to 175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Electrical Characteristics

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC Blocking Voltage	V_{DC}	$T_J = 25^{\circ}C$	1200			V
Forward Voltage	V_F	$I_F = 20A, T_J = 25^{\circ}C$		1.45	1.8	V
		$I_F = 20A, T_J = 125^{\circ}C$		1.8		V
		$I_F = 20A, T_J = 175^{\circ}C$		2.0		V
Reverse Current	I_R	$V_R = 1200V, T_J = 25^{\circ}C$		10	200	μA
		$V_R = 1200V, T_J = 125^{\circ}C$		20	250	μA
		$V_R = 1200V, T_J = 175^{\circ}C$		50	300	μA
Total Capacitive Charge	Q_C	$V_R = 800V, T_J = 25^{\circ}C$		93		nC
Total Capacitance	C	$V_R = 1V, T_J = 25^{\circ}C,$ Freq = 1MHz		1120		pF
		$V_R = 400V, T_J = 25^{\circ}C,$ Freq = 1MHz		92		
		$V_R = 800V, T_J = 25^{\circ}C,$ Freq = 1MHz		62		

Note: This is a majority carrier diode, so there is no reverse recovery charge

Thermal Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance	$R_{th(j-c)}$	junction-case		0.6	0.75	$^{\circ}C/W$

Ordering Information

Order number	Package	Marking	Operation Temperature Range	MSL Grade	Ship,Quantity	Green
SMSC015SDA120B	TO-247-2	SC4D15120H	-55 to 175 $^{\circ}C$	1	TUBE,450	Rohs

Typical Electrical Curves

Figure 1. Forward Characteristics

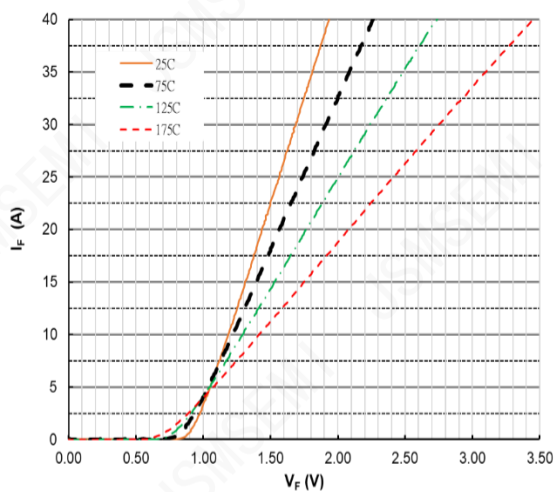


Figure 2. Forward Characteristics

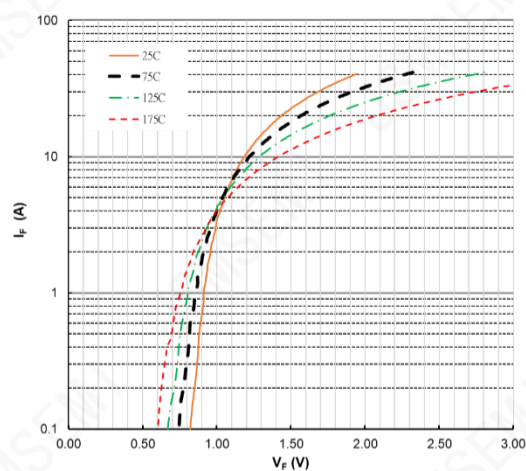


Figure 3. Reverse Characteristics

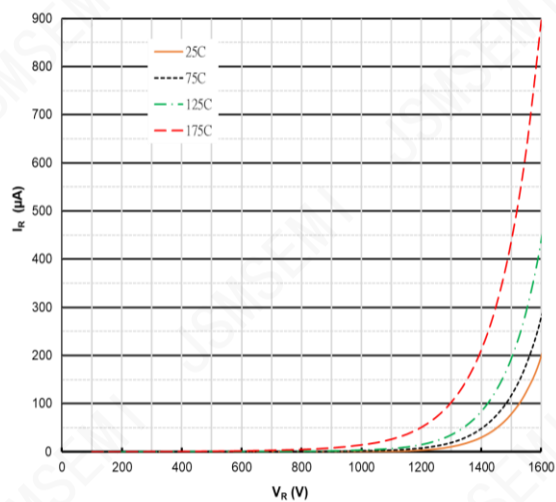


Figure 4. Power Derating

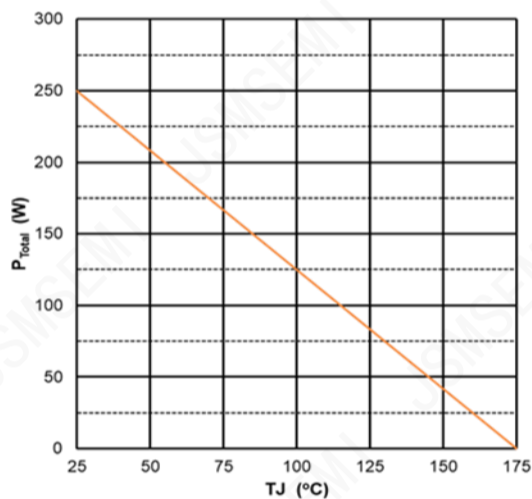


Figure 5. Reverse charge vs. Reverse Voltage

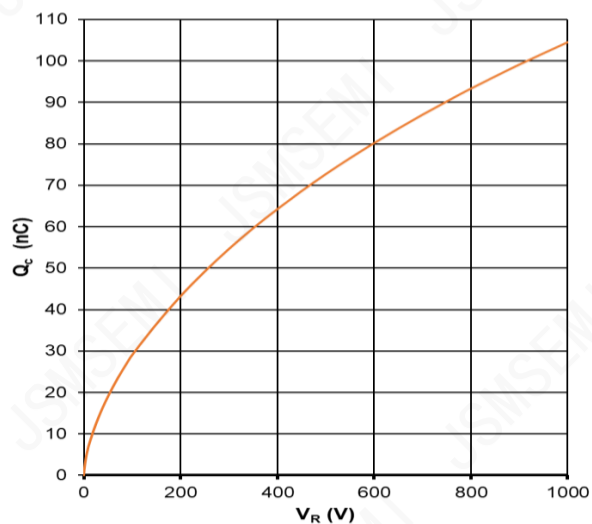
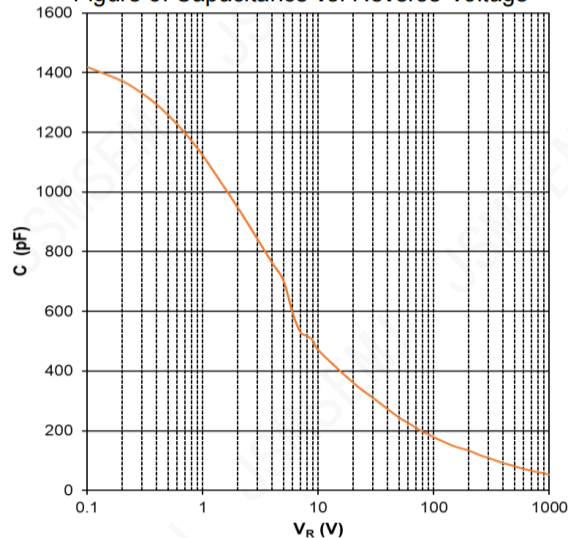
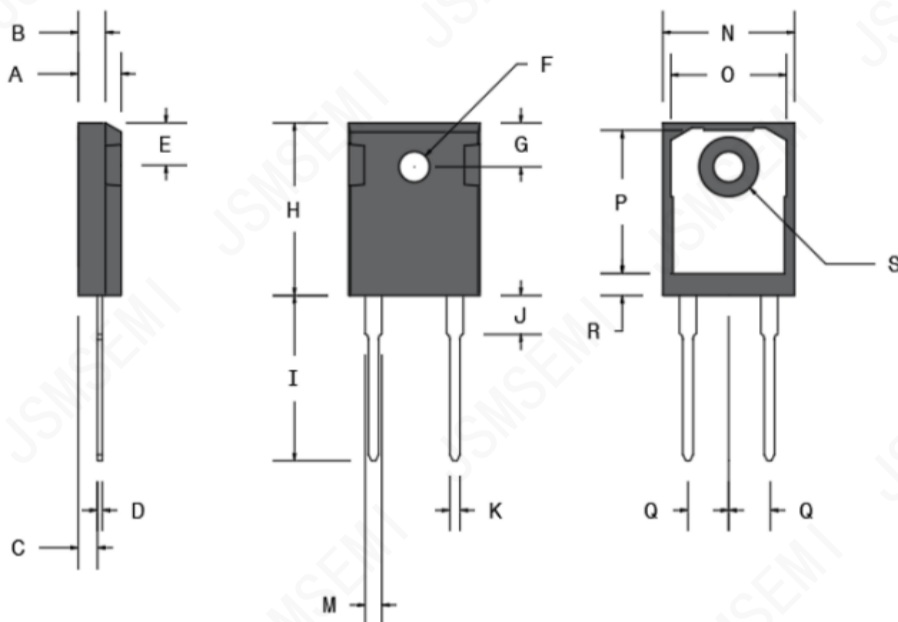


Figure 6. Capacitance vs. Reverse Voltage



Package Dimensions

(TO-247-2 Package)



SYMBOL	MIN	MAX	MIN	MAX
	[mm]	[mm]	[INCH]	[INCH]
A	4.69	5.31	0.185	0.209
B	1.49	2.49	0.059	0.098
C	2.21	2.59	0.087	0.102
D	0.40	0.79	0.016	0.031
E	5.38	6.20	0.212	0.244
F	3.50	3.81	0.138	0.150
G	6.15BSC		0.242BSC	
H	20.80	21.46	0.819	0.845
I	19.81	20.32	0.780	0.800
J	4.00	4.50	0.157	0.177
K	1.01	1.40	0.040	0.055
L	2.87	3.12	0.113	0.123
M	1.65	2.13	0.065	0.084
N	15.49	16.26	0.610	0.640
O	13.50	14.50	0.531	0.571
P	16.50	17.50	0.650	0.689
Q	5.45BSC		0.215BSC	
R	2.00	2.75	0.079	0.108
S	7.10	7.50	0.280	0.295

Revision History

Rev.	Change	Date
V1.0	Initial version	2/23/2022

Important Notice

JSMSEMI Semiconductor (JSMSEMI) PRODUCTS ARE NEITHER DESIGNED NOR INTENDED FOR USE IN MILITARY AND/OR AEROSPACE, AUTOMOTIVE OR MEDICAL DEVICES OR SYSTEMS UNLESS THE SPECIFIC JSMSEMI PRODUCTS ARE SPECIFICALLY DESIGNATED BY JSMSEMI FOR SUCH USE. BUYERS ACKNOWLEDGE AND AGREE THAT ANY SUCH USE OF JSMSEMI PRODUCTS WHICH JSMSEMI HAS NOT DESIGNATED FOR USE IN MILITARY AND/OR AEROSPACE, AUTOMOTIVE OR MEDICAL DEVICES OR SYSTEMS IS SOLELY AT THE BUYER' S RISK.

JSMSEMI assumes no liability for application assistance or customer product design. Customers are responsible for their products and applications using JSMSEMI products.

Resale of JSMSEMI products or services with statements diferent from or beyond the parameters stated by JSMSEMI for that product or service voids all express and any implied warranties for the associated JSMSEMI product or s ervice. JSMSEMI is not responsible or liable for any such statements.

JSMSEMI All Rights Reserved. Information and data in this document are owned by JSMSEMI wholly and may not be edited, reproduced, or redistributed in any way without the express written consent from JSMSEMI.

Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the JSMSEMI product that you intend to use.

For additional information please contact Kevin@ jsmsemi.com or visit www.jssemi.com